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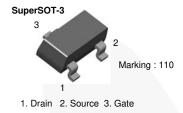


February 2015

# MMBFJ110 N-Channel Switch

## **Features**

- This device is designed for digital switching applications where very low on resistance is mandatory.
- · Sourced from process 58



# **Ordering Information**

| Part Number | Top Mark | Package | Packing Method |
|-------------|----------|---------|----------------|
| MMBFJ110    | 110      | SSOT 3L | Tape and Reel  |

# Absolute Maximum Ratings(1), (2)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^{\circ}\text{C}$  unless otherwise noted.

| Symbol           | Parameter                 | Value      | Unit |
|------------------|---------------------------|------------|------|
| $V_{DG}$         | Drain-Gate Voltage        | 25         | V    |
| V <sub>GS</sub>  | Gate-Source Voltage       | -25        | V    |
| I <sub>GF</sub>  | Forward Gate Current      | 10         | mA   |
| TJ               | Junction Temperature      | 150        | °C   |
| T <sub>STG</sub> | Storage Temperature Range | -55 to 150 | °C   |

#### Notes:

- 1. These ratings are based on a maximum junction temperature of 150°C.
- 2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty-cycle operations.

# Thermal Characteristics(3)

Values are at  $T_A = 25$ °C unless otherwise noted.

| Symbol          | Parameter                               | Value | Unit  |
|-----------------|---|-------|-------|
| P <sub>D</sub>  | Total Device Dissipation                | 460   | mW    |
|                 | Derate Above 25°C                       | 3.68  | mW/°C |
| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Ambient | 270   | °C/W  |

## Note:

3. Device mounted on FR-4 PCB 36mm × 18mm × 1.5mm; mounting pad for the collector lead minimum 6cm<sup>2</sup>.

## **Electrical Characteristics**

Values are at  $T_A = 25$ °C unless otherwise noted.

| Symbol   | Parameter                                      | Conditions  | Min. | Max. | Unit |
|--|--|---|------|------|------|
| Off Characte                                   | eristics                                       |   |      |      |      |
| V <sub>(BR)GSS</sub>                           | Gate-Source Breakdown Voltage                  | $I_G = -10 \ \mu A, \ V_{DS} = 0$                               | -25  |      | V    |
| I <sub>GSS</sub>                               | Gate Reverse Current                           | $V_{GS} = -15 \text{ V}, V_{DS} = 0$                            |      | -3.0 | nA   |
|  |  | $V_{GS} = -15 \text{ V}, V_{DS} = 0, T_A = 100^{\circ}\text{C}$ |      | -200 |      |
| $V_{GS}(off)$                                  | Gate-Source Cut-Off Voltage                    | $V_{DS} = 15 \text{ V}, I_{D} = 10 \text{ nA}$                  | -0.5 | -4.0 | V    |
| On Characte                                    | eristics                                       |   |      |      |      |
| I <sub>DSS</sub>                               | Zero-Gate Voltage Drain Current <sup>(4)</sup> | $V_{DS} = 15 \text{ V}, V_{GS} = 0$                             | 10   |      | mA   |
| r <sub>DS</sub> (on)                           | Drain-Source On Resistance                     | $V_{DS} \le 0.1 \ V, \ V_{GS} = 0$                              |      | 18   | Ω    |
| Small Signal                                   | Characteristics                                |   |      |      |      |
| $C_{dg}(on)$<br>$C_{sg}(on)$                   | Drain-Gate &Source-Gate On Capacitance         | $V_{DS} = 0, V_{GS} = 0, f = 1.0 \text{ MHz}$                   |      | 85   | pF   |
| C <sub>dg</sub> (off)<br>C <sub>sg</sub> (off) | Drain-Gate & Source-Gate Off Capacitance       | $V_{DS} = 0$ , $V_{GS} = -10$ V, $f = 1.0$ MHz                  |      | 15   | pF   |

### Note:

4. Pulse test: pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2%.

## **Typical Performance Characteristics**

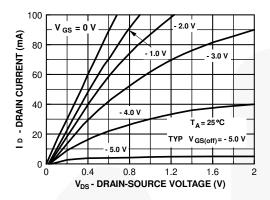
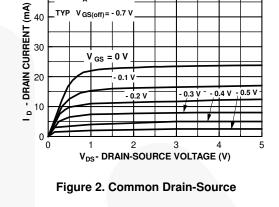


Figure 1. Common Drain-Source



TA = 25°C

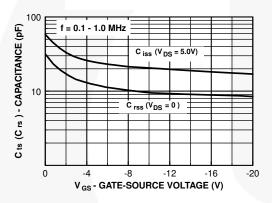
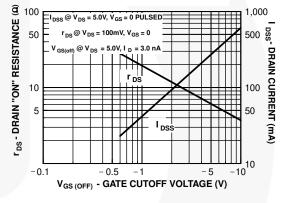


Figure 3. Capacitance vs. Gate-Source Voltage



**Figure 4. Parameter Interactions** 

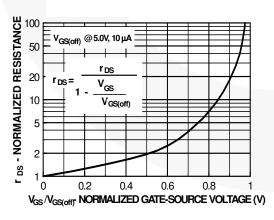


Figure 5. Normalized Drain Resistance vs. Bias Voltage

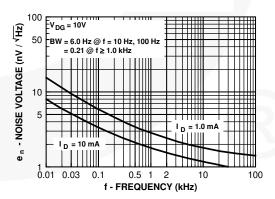


Figure 6. Noise Voltage vs. Frequency

## **Typical Performance Characteristics** (Continued)

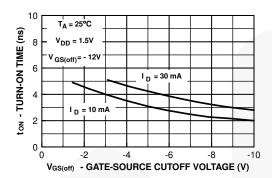


Figure 7. Switching Turn-On Time vs. Gate-Source Cutoff Voltage

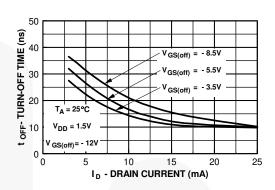


Figure 8. Switching Turn-On Time vs. Drain Current

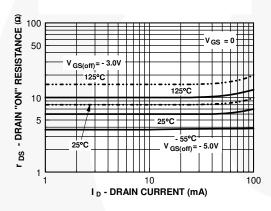


Figure 9. On Resistance vs. Drain Current

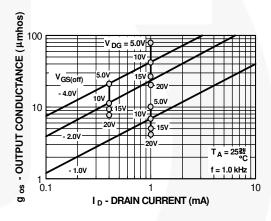


Figure 10. Output Conductance vs. Drain Current

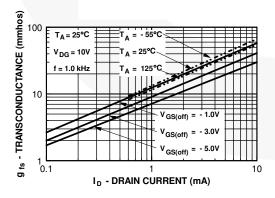


Figure 11. Transconductance vs. Drain Current

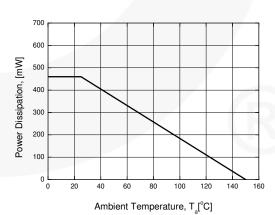


Figure 12. Power Dissipation vs Ambient Temperature

# **Physical Dimensions** 0.95 2.92±0.12-3 1.40 1.40±0.12 2.20 2 0.508 0.382 (0.29) -1.00 ⊕ 0.20M A B 0.95 -1.90 -1.90 LAND PATTERN RECOMMENDATION SEE DETAIL A--1.12 MAX 0.10 (0.94)☐ 0.10M C $2.51\pm0.20$ GAGE PLANE NOTES: UNLESS OTHERWISE SPECIFIED 0.20 NO JEDEC REFERENCE AS OF AUGUST 2003 ALL DIMENSIONS ARE IN MILLIMETERS. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS. DIMENSIONING AND TOLERANCING PER ASME Y14.5M — 1994. SEATING **PLANE** (0.56)DETAIL A SCALE: 50:1 MA03BREVB

Figure 13. MOLDED PACKAGE, SUPERSOT, 3-LEAD



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